Preferred Devices

Dual General Purpose Transistors

PNP Duals

These transistors are designed for general purpose amplifier applications. They are housed in the SOT-363/SC-88 which is designed for low power surface mount applications.

• Device Marking:

BC856BDW1T1 = 3B

BC857BDW1T1 = 3F

BC857CDW1T1 = 3G

BC858CDW1T1 = 3L

MAXIMUM RATINGS

Rating	Symbol	BC856	BC857	BC858	Unit
Collector - Emitter Voltage	V _{CEO}	-65	-45	-30	V
Collector - Base Voltage	V _{CBO}	-80	-50	-30	V
Emitter-Base Voltage	V _{EBO}	-5.0	-5.0	-5.0	V
Collector Current – Continuous	I _C	-100	-100	-100	mAdc

THERMAL CHARACTERISTICS

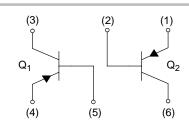
Characteristic	Symbol	Max	Unit
Total Device Dissipation Per Device FR-5 Board (Note 1) T _A = 25°C	P _D	380 250 3.0	mW/°C
Derate Above 25°C		0.0	111117
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	328	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C

1. $FR-5 = 1.0 \times 0.75 \times 0.062$ in



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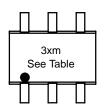
http://onsemi.com



DEVICE MARKING



SOT-363/SC-88 CASE 419B Style 1



3x = Specific Device Code

x = B, F, G, K, L

 $\mathsf{M} \ = \mathsf{Date} \ \mathsf{Code}$

ORDERING INFORMATION

Device	Package	Shipping [†]
BC856BDW1T1	SOT-363	3000 Units/Reel
BC856BDW1T1G	SOT-363 (Pb-Free)	3000 Units/Reel
BC857BDW1T1	SOT-363	3000 Units/Reel
BC857BDW1T1G	SOT-363 (Pb-Free)	3000 Units/Reel
BC857CDW1T1	SOT-363	3000 Units/Reel
BC857CDW1T1G	SOT-363 (Pb-Free)	3000 Units/Reel
BC858CDW1T1	SOT-363	3000 Units/Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Chara	cteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS		·				
Collector – Emitter Breakdown Voltage (I _C = –10 mA)	BC856 Series BC857 Series BC858 Series	V _(BR) CEO	-65 -45 -30	- - -	- - -	V
Collector – Emitter Breakdown Voltage ($I_C = -10 \mu A, V_{EB} = 0$)	BC856 Series BC857B Only BC858 Series	V _(BR) CES	-80 -50 -30	- - -	- - -	V
Collector – Base Breakdown Voltage ($I_C = -10 \mu A$)	BC856 Series BC857 Series BC858 Series	V _(BR) CBO	-80 -50 -30	- - -	- - -	V
Emitter – Base Breakdown Voltage ($I_E = -1.0 \mu A$)	BC856 Series BC857 Series BC858 Series	V _{(BR)EBO}	-5.0 -5.0 -5.0	- - -	- - -	V
Collector Cutoff Current ($V_{CB} = -30 \ V_{CB} =$	I _{CBO}	-	- -	-15 -4.0	nA μA	
ON CHARACTERISTICS				1	1	ı
, , , , ,	C856B, BC857B C857C, BC858C	h _{FE}	- -	150 270	- -	-
(O)	C856B, BC857B C857C, BC858C		220 420	290 520	475 800	
Collector – Emitter Saturation Voltage ($I_C = -10$ mA, $I_B = -0.5$ mA) ($I_C = -100$ mA, $I_B = -5.0$ mA)		V _{CE(sat)}		_ _	-0.3 -0.65	V
Base – Emitter Saturation Voltage ($I_C = -10 \text{ mA}, I_B = -0.5 \text{ mA}$) ($I_C = -100 \text{ mA}, I_B = -5.0 \text{ mA}$)		V _{BE(sat)}		-0.7 -0.9	- -	V
Base – Emitter On Voltage ($I_C = -2.0$ mA, $V_{CE} = -5.0$ V) ($I_C = -10$ mA, $V_{CE} = -5.0$ V)		V _{BE(on)}	-0.6 -	- -	-0.75 -0.82	V
SMALL-SIGNAL CHARACTERISTIC	s					
Current – Gain – Bandwidth Product ($I_C = -10$ mA, $V_{CE} = -5.0$ Vdc, $f = -6.0$		f _⊤	100	_	_	MHz
Output Capacitance (V _{CB} = -10 V, f = 1.0 MHz)		C _{ob}	-	_	4.5	pF
Noise Figure ($I_C = -0.2 \text{ mA}, V_{CE} = -5.0 \text{ Vdc}, R_S$ f = 1.0 kHz, BW = 200 Hz)	= 2.0 kΩ,	NF	-	_	10	dB

TYPICAL CHARACTERISTICS - BC856

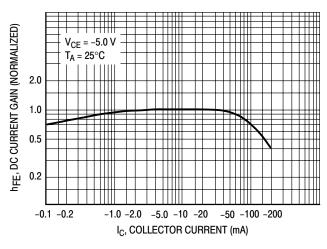


Figure 1. DC Current Gain

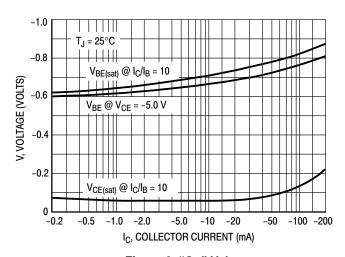


Figure 2. "On" Voltage

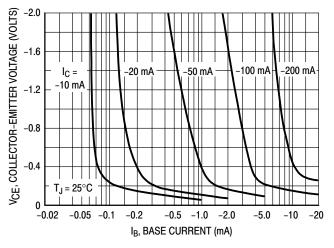


Figure 3. Collector Saturation Region

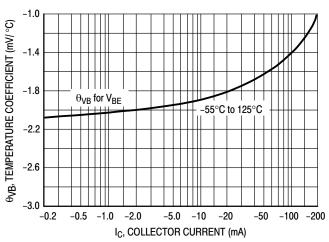


Figure 4. Base-Emitter Temperature Coefficient

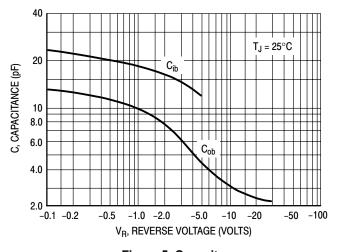


Figure 5. Capacitance

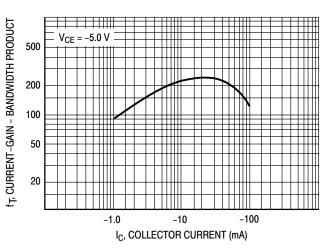
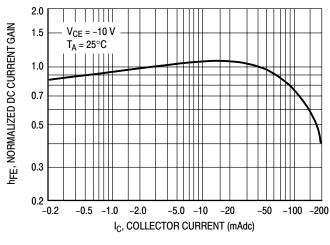


Figure 6. Current-Gain - Bandwidth Product

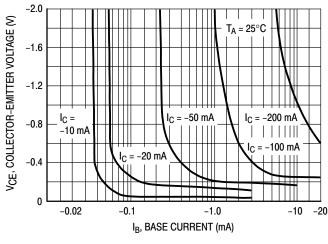
TYPICAL CHARACTERISTICS - BC857/BC858



T_A = 25°C -0.9 $V_{BE(sat)} @ I_C/I_B = 10$ -0.8 -0.7 V, VOLTAGE (VOLTS) $V_{BE(on)} @ V_{CE} = -10 V$ -0.6 -0.5 -0.4 -0.3 -0.2 $V_{CE(sat)} @ I_C/I_B = 10$ -0.1 -0.1 -0.2 -1.0 -2.0 -5.0 -50 -100 IC, COLLECTOR CURRENT (mAdc)

Figure 7. Normalized DC Current Gain

Figure 8. "Saturation" and "On" Voltages



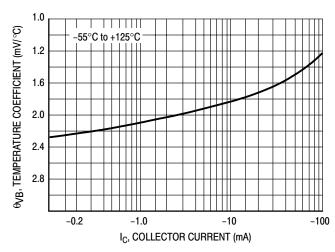
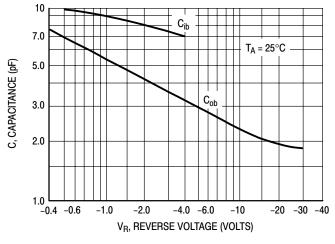


Figure 9. Collector Saturation Region

Figure 10. Base–Emitter Temperature Coefficient



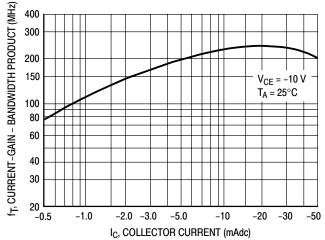


Figure 11. Capacitances

Figure 12. Current-Gain - Bandwidth Product

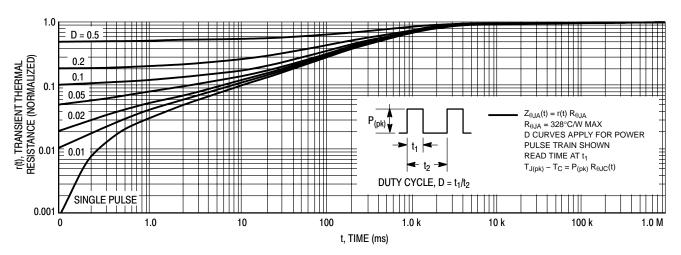


Figure 13. Thermal Response

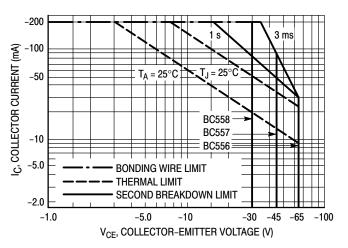


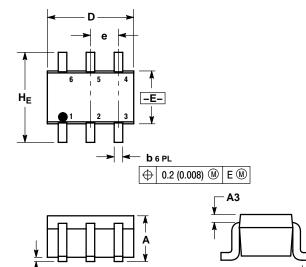
Figure 14. Active Region Safe Operating Area

The safe operating area curves indicate I_C – V_{CE} limits of the transistor that must be observed for reliable operation. Collector load lines for specific circuits must fall below the limits indicated by the applicable curve.

The data of Figure 14 is based upon $T_{J(pk)} = 150^{\circ}C$; T_{C} or T_{A} is variable depending upon conditions. Pulse curves are valid for duty cycles to 10% provided $T_{J(pk)} \leq 150^{\circ}C$. $T_{J(pk)}$ may be calculated from the data in Figure 13. At high case or ambient temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by the secondary breakdown.

PACKAGE DIMENSIONS

SC-88 (SOT-363) CASE 419B-02 ISSUE V



NOTES

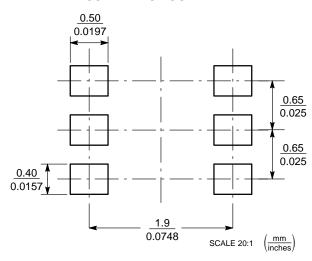
- DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.
 - 419B-01 OBSOLETE, NEW STANDARD 419B-02.

	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.80	0.95	1.10	0.031	0.037	0.043	
A1	0.00	0.05	0.10	0.000	0.002	0.004	
A3	0.20 REF		0.008 REF				
b	0.10	0.21	0.30	0.004	0.008	0.012	
С	0.10	0.14	0.25	0.004	0.005	0.010	
D	1.80	2.00	2.20	0.070	0.078	0.086	
E	1.15	1.25	1.35	0.045	0.049	0.053	
е	0.65 BSC			0.026 BSC			
L	0.10	0.20	0.30	0.004	0.008	0.012	
He	2.00	2.10	2.20	0.078	0.082	0.086	

- STYLE 1: PIN 1. EMITTER 2

 - 2. BASE 2 3. COLLECTOR 1
 - EMITTER 1
 - BASE 1
- **COLLECTOR 2**

SOLDERING FOOTPRINT*



SC-88/SC70-6

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